NEW!

GATE DRIVE TRANSFORMER FOR SIC APPLICATIONS

Next generation hardware developments often rely on SiC semiconductors, leveraging their higher switching frequency and lower losses as key application benefits. While a reduction in volume and an increase in efficiency are welcome, the need for ultra-fast switching speeds combined with very high switching frequencies in excess of 100 kHz are challenging for the component design.

The newly designed gate drive transformer **T60403-F5046-X102** is especially suited for

- Fast
- Efficient and
- Low-loss switching





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